

## ■ General Description

The AME6602 is an integrated power switch for self-powered and bus-powered Universal Serial Bus (USB) application. The AME6602 has several protections features such as current limiting and thermal shutdown to prevent catastrophic switch failure caused by increasing power dissipation when continuous heavy loads or short circuit occurs. A built-in P-channel MOSFET used for power MOS has superior Ron and easy control characteristics. The output reverse-current protection turns off the MOSFET switch whenever occurs the unexpected continuously reverse current. **FLAG** pin is an open-drain output report overcurrent or over-temperature event and has typical 8ms deglitch timeout period. AME6602 is available in SOT-25, TSOT-25A, TSOT-26A, MSOP-8 & DFN-6D(2x2x0.75mm) packages.

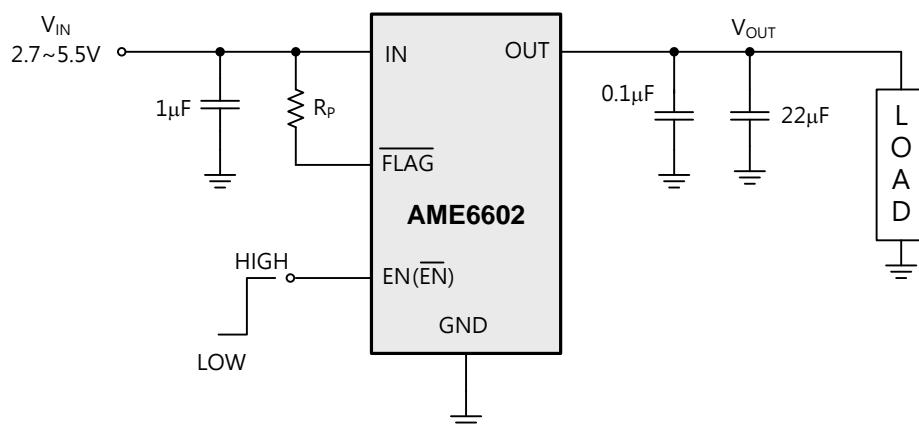
## ■ Features

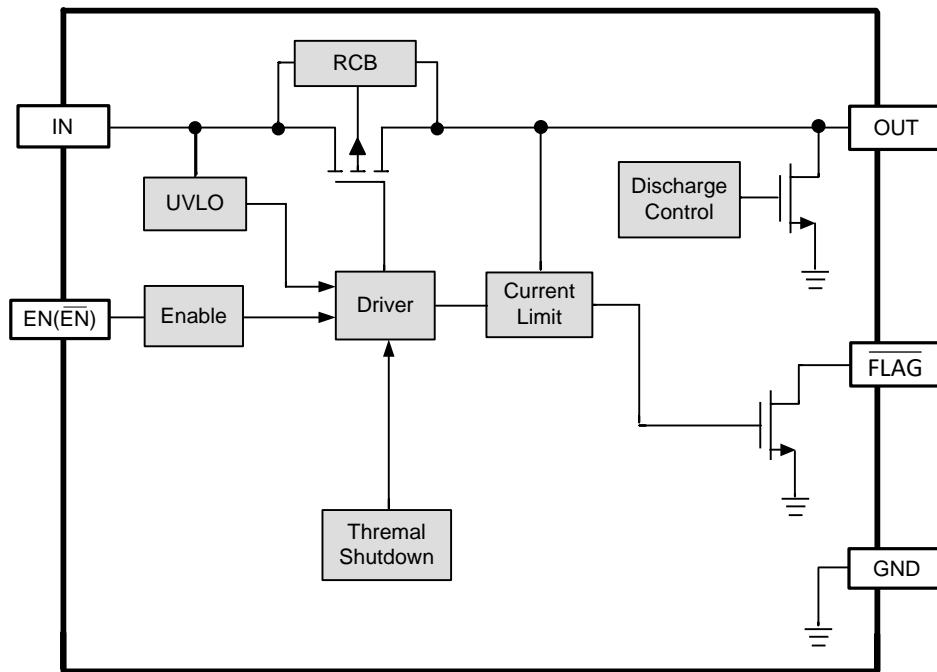
- Operating Range: 2.7V to 5.5V
- $75m\Omega$ (Typ.) High-Side MOSFET
- Constant Current during Over-Current and Current Limit with Fold-Back are Available
- Active High or Active Low Version is Available
- 1.4ms Rise Time at  $V_{IN} = 3.3V$  Condition
- Fast Short-Circuit Response:  $1.5\mu s$ (Typ.)
- Under Voltage Lockout, Over-Current, Output-Voltage and Thermal Protection
- Deglitched Open-Drain Flag Output (**FLAG**)
- UL Certification-File No. E529690

## ■ Application

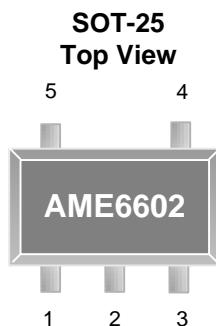
- Laptops, Desktops, AIO
- Set-Top Boxes
- LCD TVs & Monitors
- Residential Gateways
- e-Readers, Printers, Hubs
- Docking, HUB

## ■ Typical Application Schematic



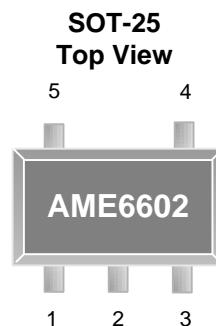
**■ Function Block Diagram**

## ■ Pin Configuration



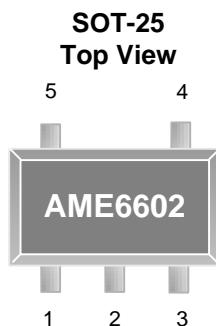
**AME6602x-AEVxxx**

1. OUT
2. GND
3. FLAG
4. EN(EN)
5. IN



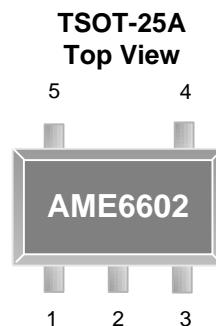
**AME6602x-BEVxxx**

1. EN(EN)
2. GND
3. FLAG
4. IN
5. OUT



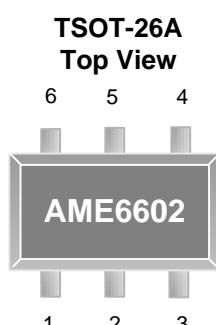
**AME6602x-CEVxxx**

1. FLAG
2. GND
3. EN(EN)
4. IN
5. OUT



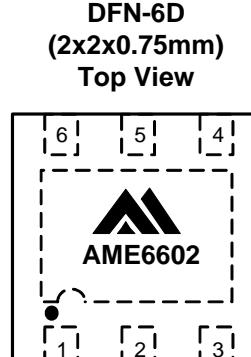
**AME6602x-AEVxxxK**

1. OUT
2. GND
3. FLAG
4. EN(EN)
5. IN



**AME6602x-AEYxxxK**

1. OUT
2. GND
3. FLAG
4. EN(EN)
5. NC
6. IN



**AME6602x-AVYxxx**

1. IN
2. GND
3. EN(EN)
4. FLAG
5. OUT
6. NC



**AME6602x-AQAxxx**

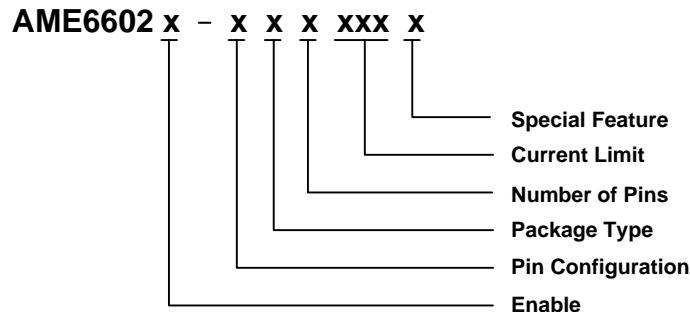
1. GND
2. IN
3. IN
4. EN(EN)
5. FLAG
6. OUT
7. OUT
8. OUT

## ■ Pin Description

Pin Name	I/O	Description	Pin Number			
			SOT-25			TSOT-25A
			A	B	C	A
IN	I	Input Voltage; Place a 1µF or greater ceramic capacitor from IN to GND as close as possible to the IC.	5	4	4	5
GND	NA	Ground connection.	2	2	2	2
OUT	O	Power-switch output.	1	5	5	1
EN	I	Enable input; logic high turns on power switch.	4	1	3	4
$\overline{EN}$	I	Enable input; logic low turns on power switch.	4	1	3	4
<u>FLAG</u>	O	Active-low open-drain output, asserted during over current, over temperature or reverse voltage conditions. Connect a 10kΩ or greater resistor pull-up, otherwise floating.	3	3	1	3

Pin Name	I/O	Description	Pin Number		
			TSOT-26A	DFN-6D	MSOP8
			A	A	A
IN	I	Input Voltage; Place a 1µF or greater ceramic capacitor from IN to GND as close as possible to the IC.	6	1	2, 3
GND	NA	Ground connection.	2	2	1
OUT	O	Power-switch output.	1	5	6, 7, 8
EN	I	Enable input; logic high turns on power switch.	4	3	4
$\overline{EN}$	I	Enable input; logic low turns on power switch.	4	3	4
<u>FLAG</u>	O	Active-low open-drain output, asserted during over current, over temperature or reverse voltage conditions. Connect a 10kΩ or greater resistor pull-up, otherwise floating.	3	4	5
NC	NA	No Connection	5	6	NA

## ■ Ordering Information



Enable	Pin Configuration	Package Type	Number of Pins	Current Limit	Special Feature
AME6602A EN Pin: Active High	A (SOT-25) (TSOT-25A) 1. OUT 2. <u>GND</u> 3. FLAG 4. EN( <u>EN</u> ) 5. IN	E: SOT-2X Q: MSOP V: DFN	V: 5 Y: 6 A: 8	100: 1.0A 150: 1.5A 200: 2.0A	Blank: For non-TSOT-2XA K: 0.9mm max height (for TSOT-2XA Only)
AME6602B EN Pin: Active Low	B (SOT-25) 1. EN( <u>EN</u> ) 2. <u>GND</u> 3. FLAG 4. IN 5. OUT				
	C (SOT-25) 1. <u>FLAG</u> 2. <u>GND</u> 3. EN( <u>EN</u> ) 4. IN 5. OUT				
	A (TSOT-26A) 1. OUT 2. <u>GND</u> 3. <u>FLAG</u> 4. EN( <u>EN</u> ) 5. NC 6. IN				
	A (DFN-6D) 1. IN 2. <u>GND</u> 3. EN( <u>EN</u> ) 4. FLAG 5. OUT 6. NC				
	A (MSOP-8) 1. GND 2. IN 3. IN 4. EN( <u>EN</u> ) 5. FLAG 6. OUT 7. OUT 8. OUT				



AME6602

## Power Distribution Switch

### ■ Absolute Maximum Ratings

Parameter	Value	Unit
Input Voltage	-0.3 to 6	V
Enable Voltage	-0.3 to 6	V
Output Voltage	-0.3 to 6	V
FLAG Voltage	-0.3 to 6	V
ESD Ratings	HBM	±4000
	MM	±200
	CDM	±1000
	IEC 61000-4-2 Contact Discharge	±8000
	IEC 61000-4-2 Air-gap Discharge	±15000

### ■ Recommended Operation Conditions

Parameter	Symbol	Rating	Unit
Input Voltage	$V_{IN}$	2.7 to 5.5	V
Ambient Temperature Range	$T_A$	-40 to +85	°C
Junction Temperature Range	$T_J$	-40 to +125	
Storage Temperature	$T_{STG}$	-60 to +150	

Part Number	Continuous Load Current	Typical Current Limit
AME6602x-xxx100x	0.5A	1A
AME6602x-xxx150x	1A	1.5A
AME6602x-xxx200x	1.5A	2A

## ■ Thermal Information

Parameter	Package	Die Attach	Symbol	Maximum	Unit
Thermal Resistance* (Junction to Case)	SOT-25	Conductive Epoxy	$\theta_{JC}$	81	°C / W
	TSOT-25A			81	
	TSOT-26A			81	
	DFN-6D			16	
	MSOP-8			80	
Thermal Resistance (Junction to Ambient)	SOT-25	Conductive Epoxy	$\theta_{JA}$	260	°C / W
	TSOT-25A			260	
	TSOT-26A			260	
	DFN-6D			66	
	MSOP-8			206	
Internal Power Dissipation	SOT-25	Conductive Epoxy	$P_D$	400	mW
	TSOT-25A			400	
	TSOT-26A			400	
	DFN-6D			1515	
	MSOP-8			625	
Lead Temperature (soldering 10 sec)**				300	°C

\* Measure  $\theta_{JC}$  on top of package.

\*\* MIL-STD-202G 210F

## ■ Electrical Specifications

$V_{IN} = 5V$ ,  $C_{IN} = 1\mu F$ ,  $C_{OUT} = 22\mu F$ ,  $R_L = 10\Omega$ ,  $T_A = 25^\circ C$ , unless otherwise specified.

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Input Voltage	$V_{IN}$		2.7		5.5	V
Quiescent Current	$I_Q$	$V_{IN} = 5V$ , Enabled, OUT = Open		70	100	$\mu A$
Shutdown Current	$I_{SHDN}$	$V_{IN} = 5.5V$ , Disabled		0.5	1	$\mu A$
Input UVLO	$V_{UVLO}$	$V_{IN}$ Rising	2	2.4	2.6	V
Switch On-Resistance	$R_{DS(ON)}$	$V_{IN} = 5.0V$		75	85	$m\Omega$
Current Limit	$I_{LIM}$	$V_{IN} = 5V$ , $V_{OUT} = 4.5V$	$AME6602x-xxx100x$	0.85	1	1.15
			$AME6602x-xxx150x$	1.275	1.5	1.75
			$AME6602x-xxx200x$	1.7	2	2.3
Short-Circuit Current Limit	$I_{Short}$	OUT Connected to GND	$AME6602x-xxx100x$		0.25	
			$AME6602x-xxx150x$		0.375	
			$AME6602x-xxx200x$		0.5	
EN Input Threshold -High	$V_{IH}$	$V_{IN} = 2.7V$ to $5.5V$	1.2			V
EN Input Threshold -Low	$V_{IL}$	$V_{IN} = 2.7V$ to $5.5V$			0.6	
Output Turn-On Rise Time	$t_R$	$V_{IN} = 5V$ , $C_L = 1\mu F$ , $R_{LOAD} = 100\Omega$	1.5	1.9	3	ms
		$V_{IN} = 3.3V$ , $C_L = 1\mu F$ , $R_{LOAD} = 100\Omega$	1	1.4	2	
FLAG Blanking Time	$t_{Blank}$	Assertion and de-assertion due to overcurrent and over-temperature condition	5.5	8	12	ms
Response Time to Short Current	$t_{IOS}$	$V_{IN} = 5V$		1.5		$\mu s$
Reverse Current Limit	$I_{ROCP}$	$V_{OUT} - V_{IN} = 150mV$		0.4		A
Time from Reverse-Voltage Condition to MOSFET Turn Off	$t_{TRIG}$	$V_{IN} = 5V$	5.5	8	12	ms
Thermal Shutdown Threshold	$T_{SHDN}$	Enabled		145		$^\circ C$
Thermal Shutdown Hysteresis	$T_{HYS}$			25		$^\circ C$

## ■ Application Information

### Supply Filtering

A  $1\mu\text{F}$  bypass capacitor from IN to GND, placed near the AME6602, is strongly recommended to control supply transients. Without a bypass capacitor, an output short may cause sufficient ringing on the input (from supply lead inductance) to damage internal control circuitry. Input transients must not exceed the absolute maximum supply voltage ( $V_{IN}$  max = 6V) even for a short duration.

### ON and OFF Control

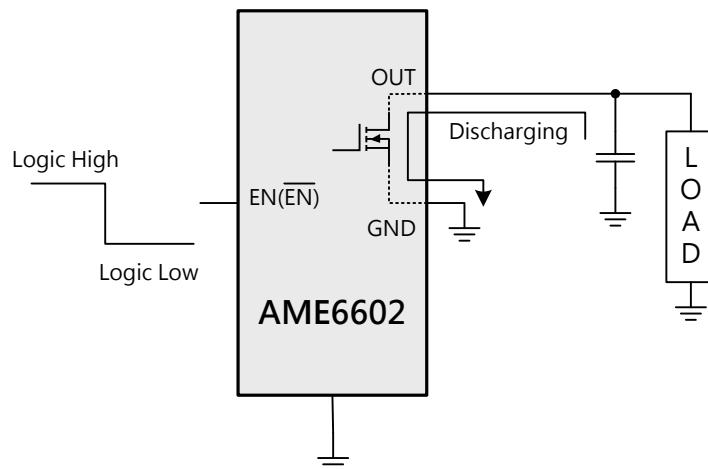
$\text{EN}(\overline{\text{EN}})$  must be driven logic high or logic low for a clearly defined input. Floating the input may cause unpredictable operation. The pin should not be allowed to go negative with respect to GND.

### Auto Output Discharge

The discharge function is activated when  $\text{EN}(\overline{\text{EN}})$  pin is disabled or de-asserted. The power switch automatically offers a resistive discharge path for the external storage capacitor. This facilitates discharging any residue of the output voltage when either no external output resistance or load resistance is present at the output.

EN	IN to OUT	OUT to GND
H	ON	OFF
L	OFF	ON

EN	IN to OUT	OUT to GND
H	OFF	ON
L	ON	OFF



## ■ Application Information (Contd.)

### FLAG Indicator

The FLAG open-drain output is asserted (FLAG: active low) during an over-current or over-temperature condition. Until the fault condition is de-asserted and the AME6602 resumes normal operation. The AME6602 eliminate false FLAG reporting by using an internal delay "deglitch" circuit for over-current (8ms typ.) conditions without the need for external circuitry. This ensures that FLAG is not accidentally asserted due to normal operation such as starting into a heavy capacitive load.

### Power Dissipation

Thermal analysis is strongly dependent on additional system level factors such as air flow, board layout, copper thickness and surface area, and proximity to other devices dissipating power.

Good thermal design practice must include all system level factors in addition to individual component analysis. Begin by determining the  $R_{DS(ON)}$  of the internal MOSFET relative to the input voltage and operating temperature. As an initial estimate, make use of the highest operating ambient temperature of interest and read  $R_{DS(ON)}$  from the typical characteristics graph. Using this value, the power dissipation can be calculated by:

$$P_D = R_{DS(ON)} \times (I_{OUT})^2$$

Where:

$P_D$  = Total power dissipation (W)

$R_{DS(ON)}$  = MOSFET on-resistance ( $\Omega$ )

$I_{OUT}$  = Maximum current-limit threshold (A)

This step calculates the total power dissipation of internal MOSFET.

Next, the junction temperature of the device depends on different contributing factors such as board layout, ambient temperature, device environment, and so on. Then, calculate the junction temperature:

$$T_J = P_D \times \theta_{JA} + T_A$$

Where:

$T_A$  = Ambient temperature ( $^{\circ}\text{C}$ )

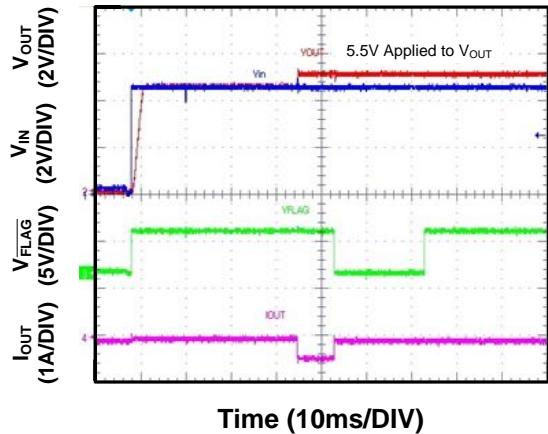
$\theta_{JA}$  = Thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$P_D$  = Total power dissipation (W)

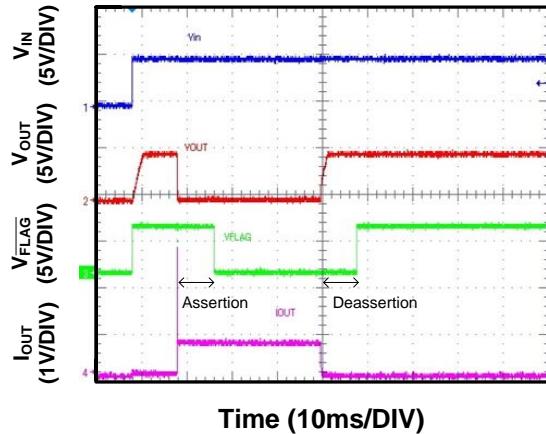
Compare the calculated  $T_J$  with the initial estimate. If they are not within a few degrees, repeat the calculation using the refined  $R_{DS(ON)}$  from the previous calculation as the new estimate. Two or three iterations are generally sufficient to achieve the desired result. The final  $T_J$  is highly dependent on  $\theta_{JA}$  and thermal resistance is respectably dependent on the individual package and board layout.

## ■ Characterization Curve

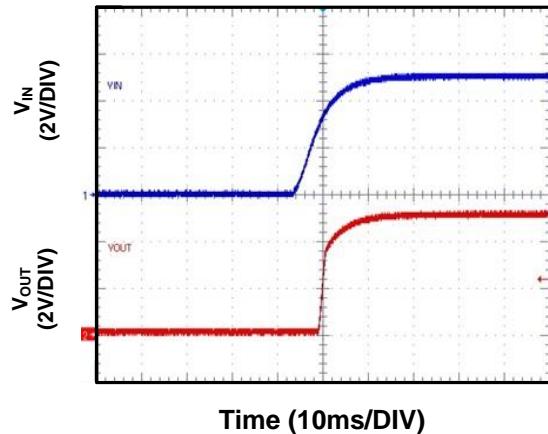
**Reverse Voltage Protection**



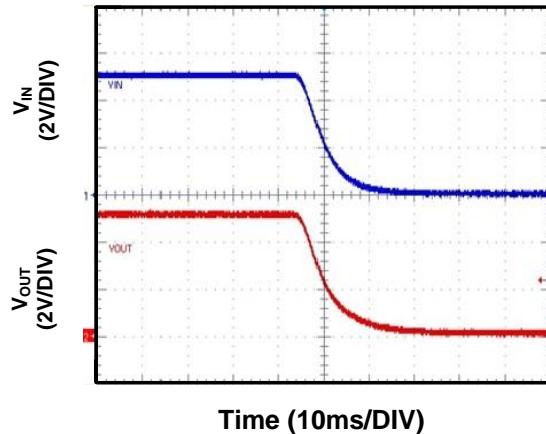
**FLAG Blanking Time**



**UVLO Protection at Rising**

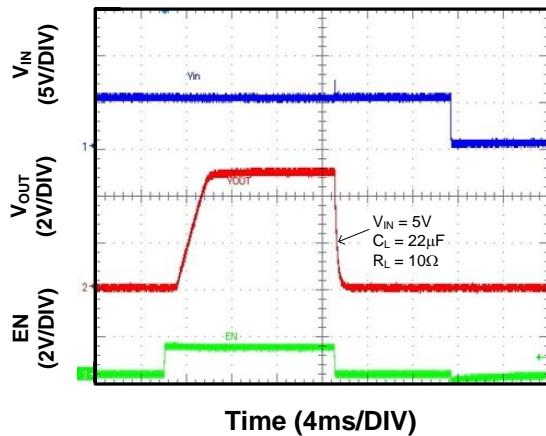


**UVLO Protection at Falling**

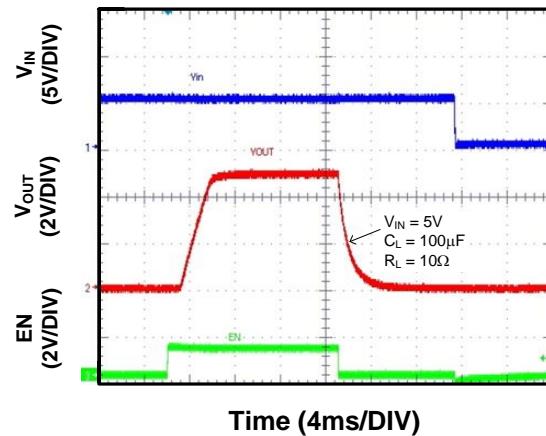


## ■ Characterization Curve (Contd.)

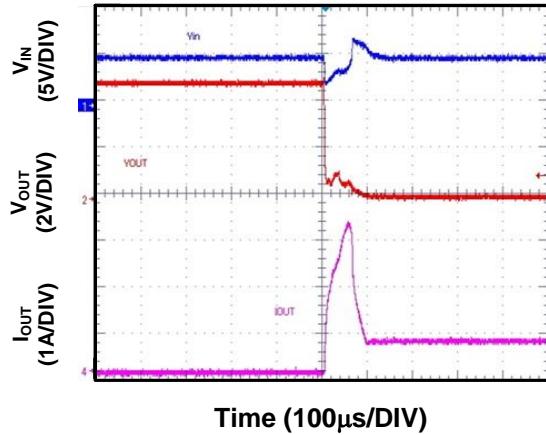
**Enable On / Off**



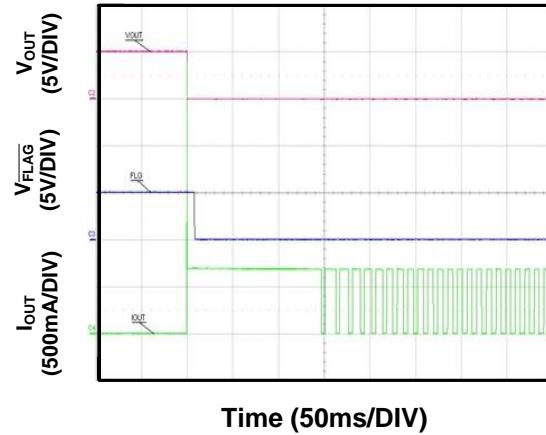
**Enable On / Off**



**Short Circuit Response**

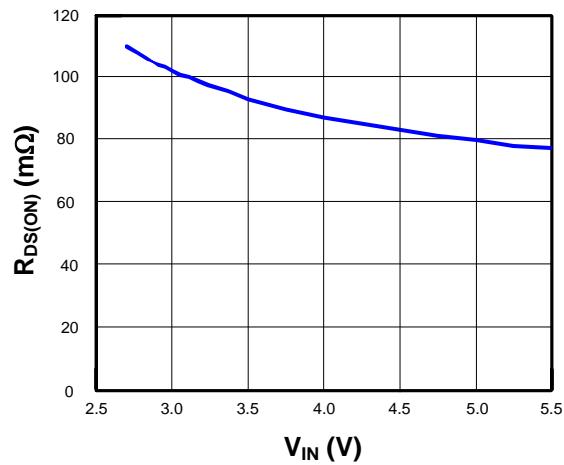


**Thermal Shutdown**

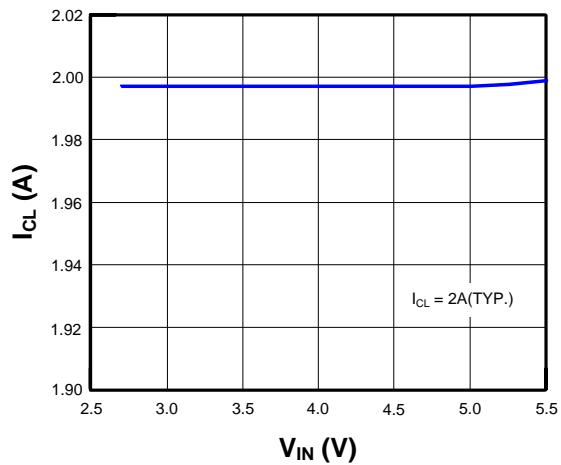


## ■ Characterization Curve (Contd.)

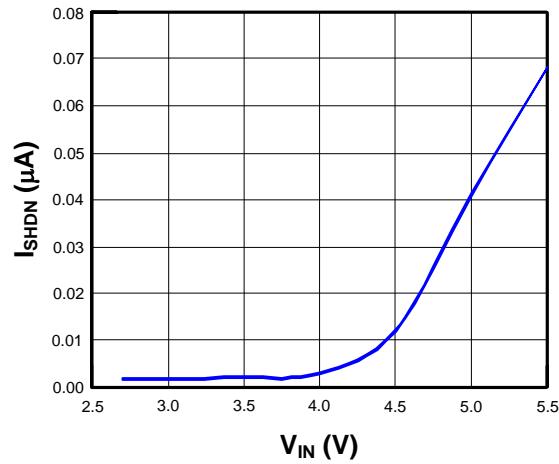
**R<sub>DS(ON)</sub> vs. V<sub>IN</sub>**



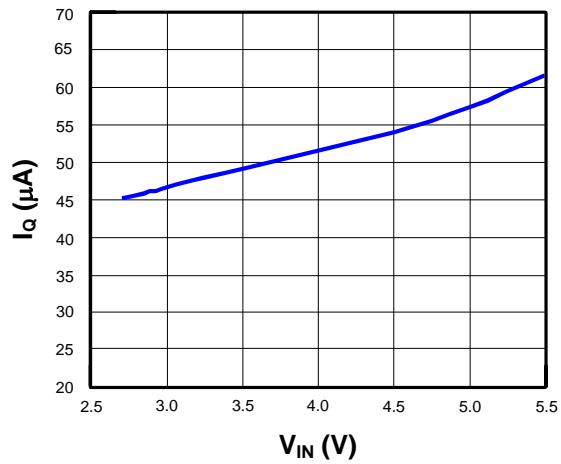
**I<sub>CL</sub> vs. V<sub>IN</sub>**



**Shutdown Current vs. V<sub>IN</sub>**

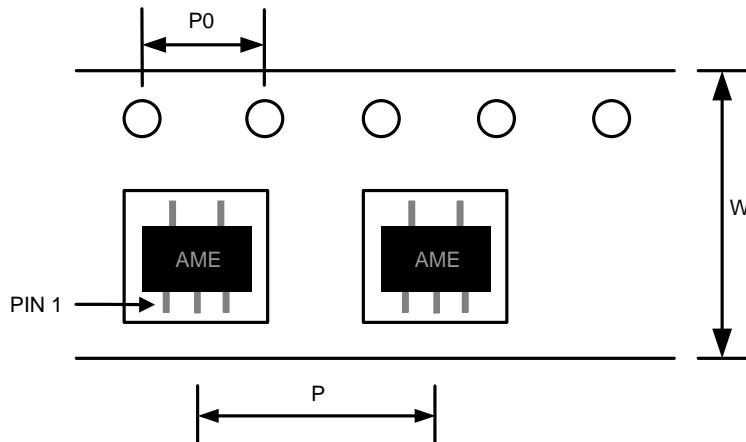


**I<sub>Q</sub> vs V<sub>IN</sub>**



## ■ Tape and Reel Dimension

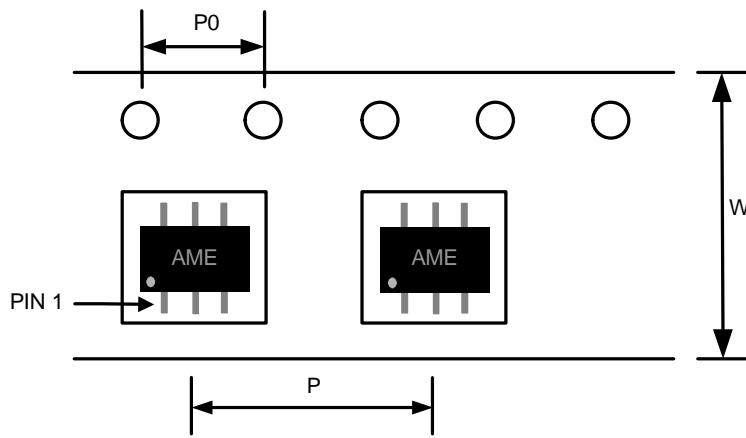
### SOT-25/TSOT-25A



Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Pitch (P0)	Part Per Full Reel	Reel Size
SOT-25/TSOT-25A	$8.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	3000pcs	$180 \pm 1$ mm

### TSOT-26A



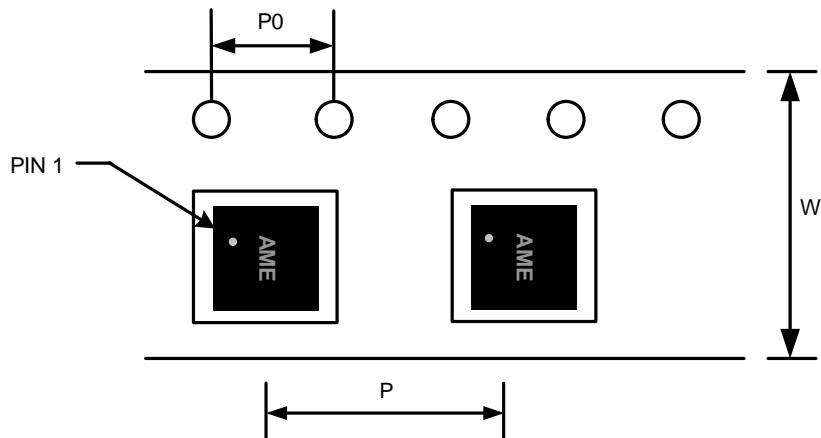
Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Pitch (P0)	Part Per Full Reel	Reel Size
TSOT-26A	$8.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	3000pcs	$180 \pm 1$ mm

## ■ Tape and Reel Dimension (Contd.)

### DFN-6D

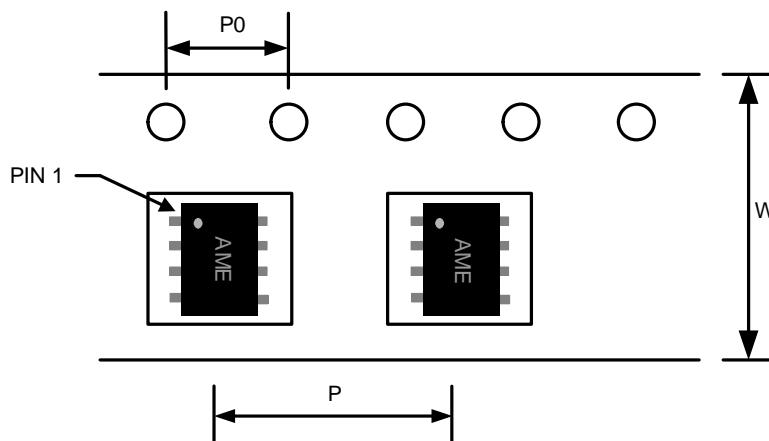
(2x2x0.75mm)



Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Pitch (P0)	Part Per Full Reel	Reel Size
DFN-6D	$8.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	3000pcs	$180 \pm 1$ mm

### MSOP-8

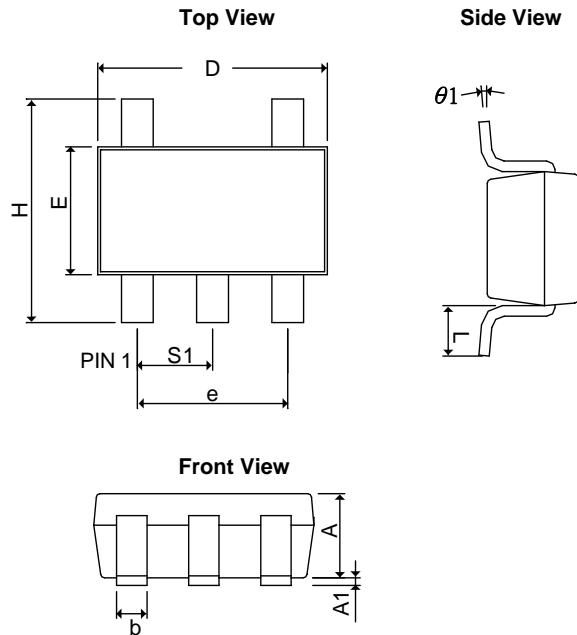


Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Pitch (P0)	Part Per Full Reel	Reel Size
MSOP-8	$12.0 \pm 0.1$ mm	$8.0 \pm 0.1$ mm	$4.0 \pm 0.1$ mm	2500pcs	$330 \pm 1$ mm

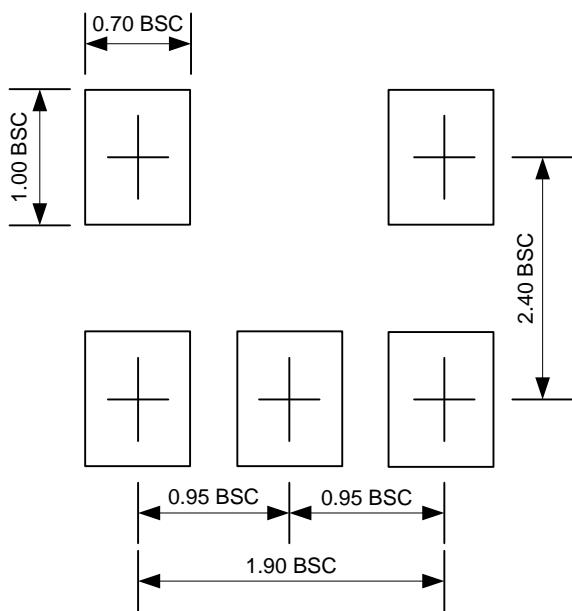
## ■ Package Dimension

**SOT-25**



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
<b>A</b>	0.90	1.30	0.0354	0.0512
<b>A<sub>1</sub></b>	0.00	0.15	0.0000	0.0059
<b>b</b>	0.30	0.55	0.0118	0.0217
<b>D</b>	2.70	3.10	0.1063	0.1220
<b>E</b>	1.40	1.80	0.0551	0.0709
<b>e</b>	1.90 BSC		0.0748 BSC	
<b>H</b>	2.60	3.00	0.1024	0.1181
<b>L</b>	0.37 BSC		0.0146 BSC	
<b>θ1</b>	0°	10°	0°	10°
<b>S<sub>1</sub></b>	0.95 BSC		0.0374 BSC	

## ■ Lead Pattern

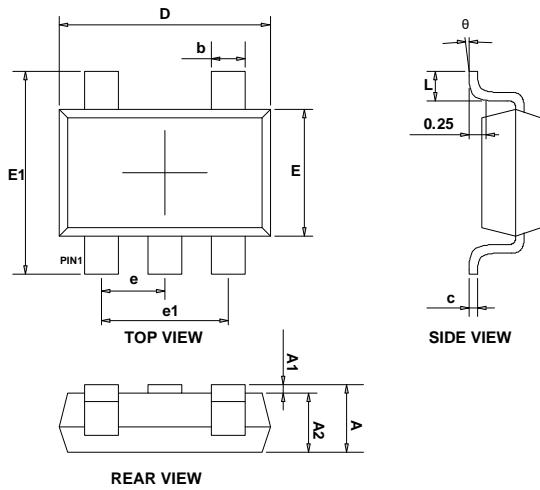


Note:

1. Lead pattern unit description:  
BSC: Basic. Represents theoretical exact dimension or dimension target.
2. Dimensions in Millimeters.
3. General tolerance  $\pm 0.05\text{mm}$  unless otherwise specified.

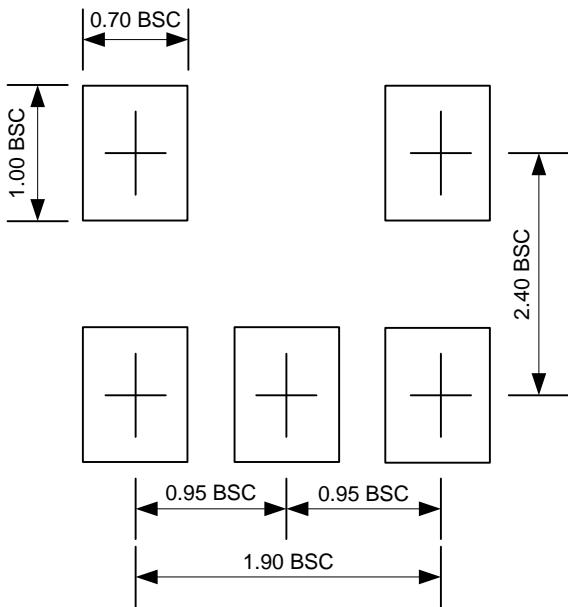
## ■ Package Dimension (Contd.)

### TSOT-25A



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
<b>A</b>	0.700	0.900	0.028	0.035
<b>A1</b>	0.000	0.100	0.000	0.004
<b>A2</b>	0.700	0.800	0.028	0.031
<b>b</b>	0.350	0.500	0.014	0.020
<b>c</b>	0.080	0.200	0.003	0.008
<b>D</b>	2.820	3.020	0.111	0.119
<b>E</b>	1.600	1.700	0.063	0.067
<b>E1</b>	2.650	2.950	0.104	0.116
<b>e</b>	0.95 BSC		0.037 BSC	
<b>e1</b>	1.90 BSC		0.075 BSC	
<b>L</b>	0.300	0.600	0.012	0.024
<b>θ</b>	0°	8°	0°	8°

## ■ Lead Pattern

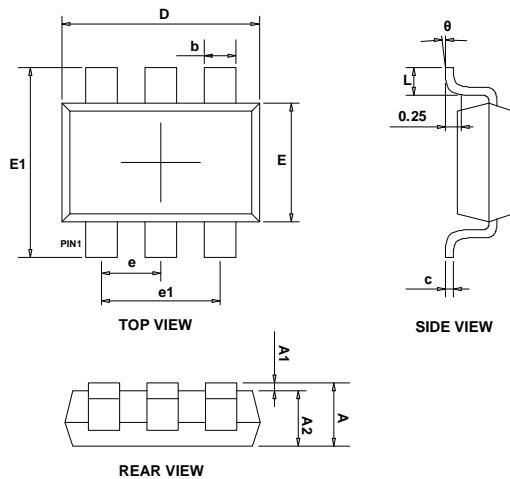


Note:

1. Lead pattern unit description:  
BSC: Basic. Represents theoretical exact dimension or dimension target.
2. Dimensions in Millimeters.
3. General tolerance  $\pm 0.05\text{mm}$  unless otherwise specified.

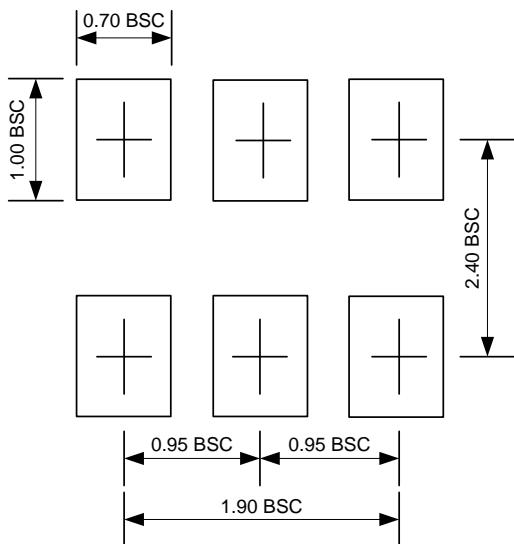
## ■ Package Dimension (Contd.)

### TSOT-26A



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
<b>A</b>	0.700	0.900	0.028	0.035
<b>A1</b>	0.000	0.100	0.000	0.004
<b>A2</b>	0.700	0.800	0.028	0.031
<b>b</b>	0.350	0.500	0.014	0.020
<b>c</b>	0.080	0.200	0.003	0.008
<b>D</b>	2.820	3.020	0.111	0.119
<b>E</b>	1.600	1.700	0.063	0.067
<b>E1</b>	2.650	2.950	0.104	0.116
<b>e</b>	0.95 BSC		0.037 BSC	
<b>e1</b>	1.90 BSC		0.075 BSC	
<b>L</b>	0.300	0.600	0.012	0.024
<b>θ</b>	0°	8°	0°	8°

## ■ Lead Pattern



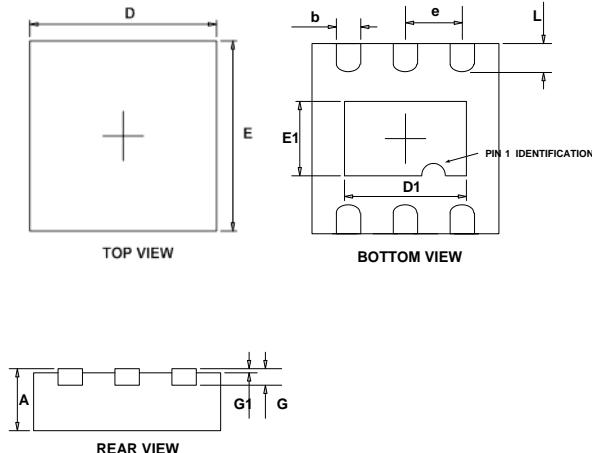
Note:

1. Lead pattern unit description:  
BSC: Basic. Represents theoretical exact dimension or dimension target.
2. Dimensions in Millimeters.
3. General tolerance  $\pm 0.05\text{mm}$  unless otherwise specified.

## ■ Package Dimension (Contd.)

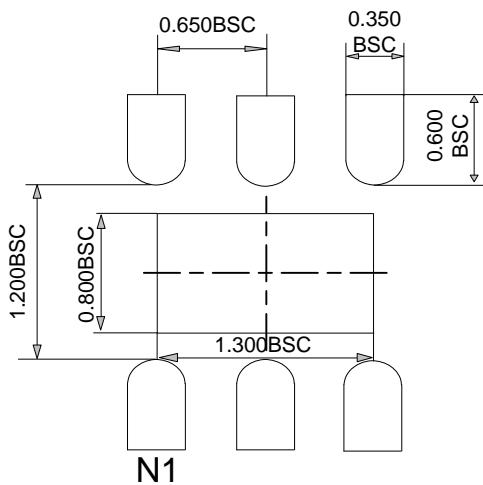
**DFN-6D**

(2x2x0.75mm)



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
<b>A</b>	0.700	0.800	0.028	0.031
<b>D</b>	1.900	2.100	0.075	0.083
<b>E</b>	1.900	2.100	0.075	0.083
<b>e</b>	0.650 TYP		0.026 TYP	
<b>D1</b>	1.100	1.650	0.043	0.065
<b>E1</b>	0.600	1.050	0.024	0.041
<b>b</b>	0.180	0.350	0.007	0.014
<b>L</b>	0.200	0.450	0.008	0.018
<b>G</b>	0.178	0.228	0.007	0.009
<b>G1</b>	0.000	0.050	0.000	0.002

## ■ Lead Pattern

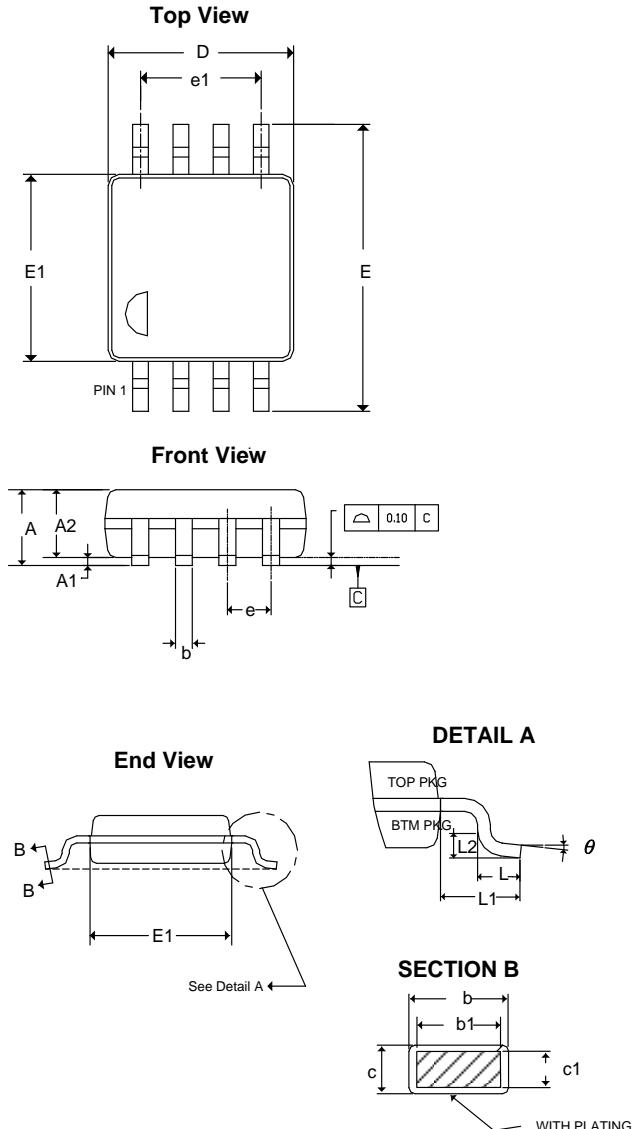


Note:

1. Lead pattern unit description:  
BSC: Basic. Represents theoretical exact dimension or dimension target.
2. Dimensions in Millimeters.
3. General tolerance  $\pm 0.05\text{mm}$  unless otherwise specified.

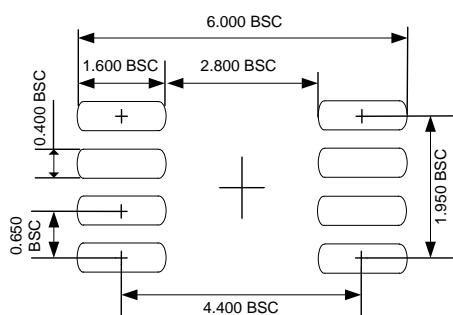
## ■ Package Dimension (Contd.)

### MSOP-8



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
<b>A</b>	-	1.10	-	0.043
<b>A<sub>1</sub></b>	0.00	0.20	0.000	0.008
<b>A<sub>2</sub></b>	0.75	0.95	0.029	0.037
<b>b</b>	0.25	0.38	0.010	0.015
<b>b<sub>1</sub></b>	0.28	0.33	0.011	0.013
<b>c</b>	0.08	0.23	0.003	0.009
<b>c<sub>1</sub></b>	0.13	0.17	0.005	0.007
<b>D</b>	2.90	3.10	0.114	0.122
<b>E</b>	4.75	5.05	0.187	0.199
<b>E<sub>1</sub></b>	2.90	3.10	0.114	0.122
<b>e</b>	0.65 TYP		0.026 TYP	
<b>e<sub>1</sub></b>	1.95 TYP		0.077 TYP	
<b>L</b>	0.40	0.80	0.016	0.031
<b>L<sub>1</sub></b>	0.94 REF		0.037 REF	
<b>L<sub>2</sub></b>	0.254 TYP		0.010 TYP	
<b>θ</b>	0°	8°	0°	8°

## ■ Lead Pattern



Note:

1. Lead pattern unit description:  
BSC: Basic. Represents theoretical exact dimension or dimension target.
2. Dimensions in Millimeters.
3. General tolerance  $\pm 0.05\text{mm}$  unless otherwise specified.



**www.ame.com.tw**  
**E-mail: sales@ame.com.tw**

**Life Support Policy:**

These products of AME, Inc. are not authorized for use as critical components in life-support devices or systems, without the express written approval of the president of AME, Inc.

AME, Inc. reserves the right to make changes in the circuitry and specifications of its devices and advises its customers to obtain the latest version of relevant information.

© AME, Inc. , January 2023

Document: P003-DS6602-B.01

**Corporate Headquarter  
AME, Inc.**

8F-1, 12, WenHu St., Nei-Hu

Taipei 114, Taiwan .

Tel: 886 2 2627-8687

Fax: 886 2 2659-2989